

TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TD62591APG, TD62592APG, TD62593APG, TD62594APG
TD62595APG, TD62595AFG, TD62596APG, TD62596AFG
TD62597APG, TD62597AFG, TD62598APG, TD62598AFG

8CH SINGLE DRIVER

The TD62591APG Series are comprised of eight NPN Transistor Arrays.

Applications include relay, hammer, lamp and display (LED) drivers.

This devices are a product for the Pb free(Sn-Ag).

FEATURES

- Output current (single output) 200 mA (Max)
- High sustaining voltage output 50V (Min)
- Low saturation voltage $V_{CE(sat)} = 0.8\text{ V}$
@ $I_{out} = 150\text{mA}$ inputs compatible with various type logic.

- ### Include Input Resistor

TD62591A, TD62595APG/FG : external.

general purpose

TD62592A, TD62596APG/FG : 10.5 k Ω + 7V

zener diode 14~25 V

PMOS

TD62593A, TD62597APG/FG : 2.7 kΩ

TTL, 5 V CMOS

TD62594A, TD62598APG/FG : 10.5 k Ω

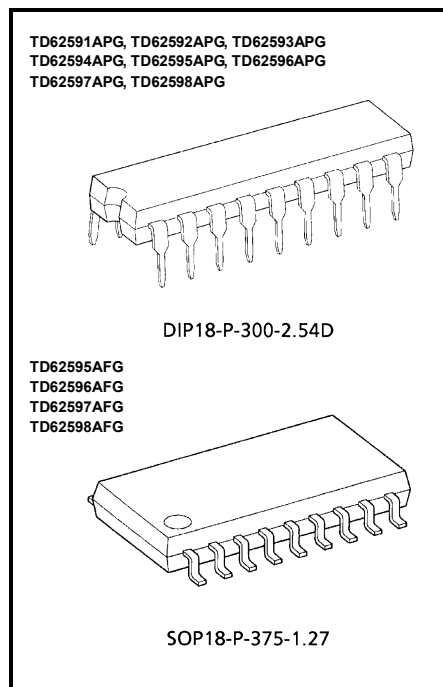
6~15 V PMOS, CMOS

- Include Clamp Diode

TD62595APG, TD62595AFG, TD62596APG, TD62596AFG

TD62597APG, TD62597AFG, TD62598APG, TD62598AFG

- Package type-APG : DIP-18pin
- Package type-AFG : SOP-18pin



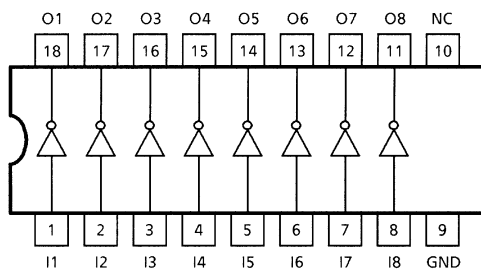
Weight

DIP18-P-300-2.54D : 1.47 g (Typ.)

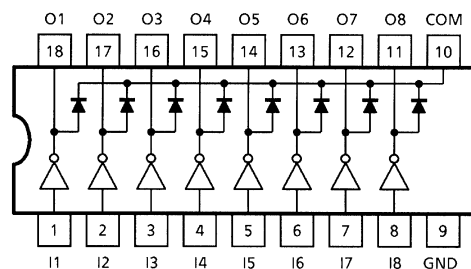
SOP18-P-375-1.27 : 0.5 g (Typ.)

PIN CONNECTION (TOP VIEW)

TD62591APG, TD62592APG, TD62593APG
TD62594APG

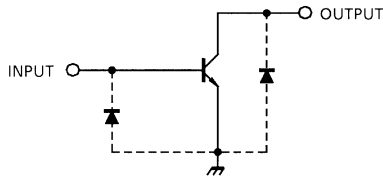


TD62595APG, TD62595AFG, TD62596APG, TD62596AFG
TD62597APG, TD62597AFG, TD62598APG, TD62598AFG

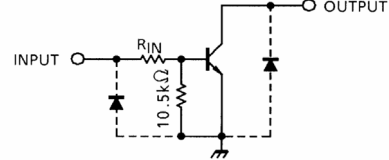


SCHEMATICS (EACH DRIVER)

TD62591APG

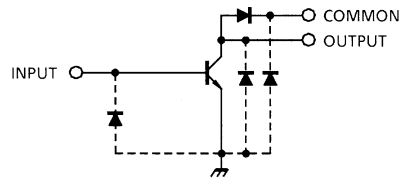


TD62592APG, TD62593APG, TD62594APG

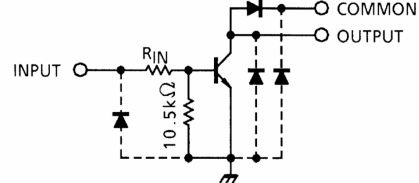


TD62592 $R_{IN} = 10.5k\Omega + V_Z = 7V$
 TD62593 $R_{IN} = 2.7k\Omega$
 TD62594 $R_{IN} = 10.5k\Omega$

TD62595APG, TD62595AFG



TD62596APG, TD62596AFG, TD62597APG,
 TD62597AFG, TD62598APG, TD62598AFG



TD62596 $R_{IN} = 10.5k\Omega + V_Z = 7V$
 TD62597 $R_{IN} = 2.7k\Omega$
 TD62598 $R_{IN} = 10.5k\Omega$

Note: The input and output parasitic diodes cannot be used as clamp diodes.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Emitter Voltage	V_{CEO}	50	V
Collector-Base Voltage	V_{CBO}	50	V
Clamp Diode Reverse Voltage	V_R (Note 1)	50	V
Collector Current	I_C	200	mA / ch
Input Voltage	V_{IN} (Note 2)	-0.5~30	V
Input Current	I_{IN} (Note 3)	25	mA
Power Dissipation	P_D (Note 4)	0.96 (Note 5) / 1.47	W
Operating Temperature	T_{opr}	-40~85	°C
Storage Temperature	T_{stg}	-55~150	°C

Note 1: Except TD62591~TD62594APG

Note 2: Except TD62591APG, TD62595APG, TD62595AFG

Note 3: Only TD62591APG, TD62595APG, TD62595AFG

Note 4: Delated above 25°C in the proportion of 11.7mW / °C (APG-Type), 7.7mW / °C (AFG-Type)

Note 5: SOP-18pin

RECOMMENDED OPERATING CONDITIONS (Ta = -40~85°C)

CHARACTERISTIC		SYMBOL	CONDITION	MIN	TYP.	MAX	UNIT
Collector-Emitter Voltage		V_{CE0}	—	0	—	50	V
Collector-Base Voltage		V_{CB0}	—	0	—	50	V
Collector Current		I_C	—	0	—	150	mA / ch
Clamp Diode Reverse Voltage		V_R	(Note1)	7	—	50	V
Input Voltage		V_{IN}	(Note2)	0	—	25	V
Input Current		I_{IN}	(Note3)	0	—	10	mA
Input Voltage (Output On)	TD62592 TD62596	$V_{IN (ON)}$	—	14.0	—	25	V
	TD62593 TD62597			2.4	—	25	
	TD62594 TD62598			7.0	—	25	
Power Dissipation	APG	P_D	—	—	—	0.52	W
	AFG		—	—	—	0.355	

ELECTRICAL CHARACTERISTICS (Ta = 25°C unless otherwise noted)

CHARACTERISTIC		SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT
Output Leakage Current		I_{CEX}	1	$V_{CE} = 50 \text{ V}, V_{IN} = 0$	—	—	10	μA
Collector-Emitter Saturation Voltage		$V_{CE (sat)}$	2	$I_C = 10 \text{ mA}, I_{IN} = 0.4 \text{ mA}$	—	—	0.2	V
				$I_C = 150 \text{ mA}, I_{IN} = 3.0 \text{ mA}$	—	—	0.8	
DC Current Transfer Ratio		h_{FE}	2	$V_{CE} = 10 \text{ V}$ $I_C = 10 \text{ mA}$	(Note 3) 70	—	—	—
					(Note 2) 50	—	—	
Input Current	TD62591 TD62595	$I_{IN (ON)}$	3	$I_C = 50 \text{ mA}$	—	—	0.65	mA
	TD62592 TD62596			$V_{IN} = 14 \text{ V}, I_C = 50 \text{ mA}$	—	—	0.9	
	TD62593 TD62597			$V_{IN} = 2.4 \text{ V}, I_C = 50 \text{ mA}$	—	—	0.9	
	TD62594 TD62598			$V_{IN} = 7.0 \text{ V}, I_C = 50 \text{ mA}$	—	—	0.9	
Turn-On Delay		t_{ON}	4	$V_{OUT} = 50 \text{ V}, R_L = 330 \Omega$	—	0.1	—	μs
Turn-Off Delay		t_{OFF}			—	0.3	—	μs

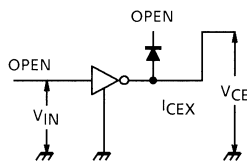
Note 1: Except TD62591~TD62594APG

Note 2: Except TD62591APG, TD62595APG, TD62595AFG

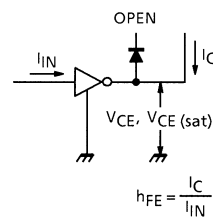
Note 3: Only TD62591APG, TD62595APG, TD62595AFG

TEST CIRCUIT

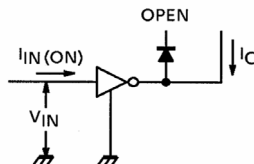
1. I_{CEX}



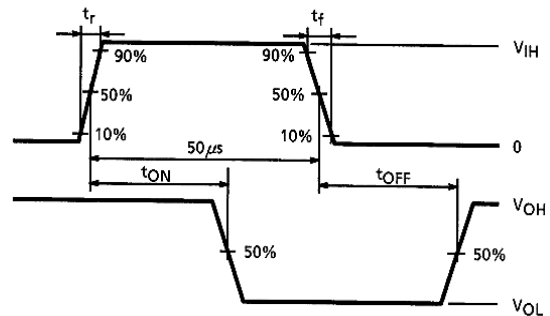
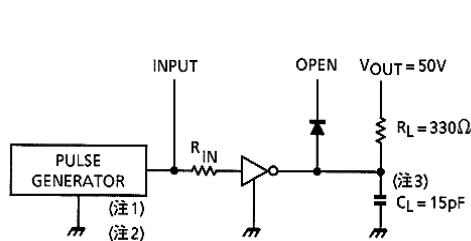
2. h_{FE} , $V_{CE(sat)}$



3. $V_{IN(ON)}$



4. t_{ON} , t_{OFF}



Note 1: Pulse width 50 μ s, duty cycle 10%
Output impedance 50 Ω , $t_r \leq 5$ ns, $t_f \leq 10$ ns

Note 2: See below

Input Condition

TYPE NUMBER	R_{IN}	V_{IH}
TD62591APG, TD62595APG, TD62595AFG	2.7 k Ω	3 V
TD62592APG, TD62596APG, TD62596AFG	0 Ω	15 V
TD62593APG, TD62597APG, TD62597AFG	0 Ω	3 V
TD62594APG, TD62598APG, TD62598AFG	0 Ω	10 V

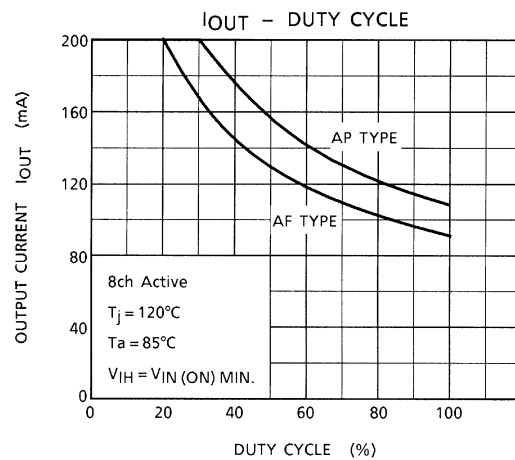
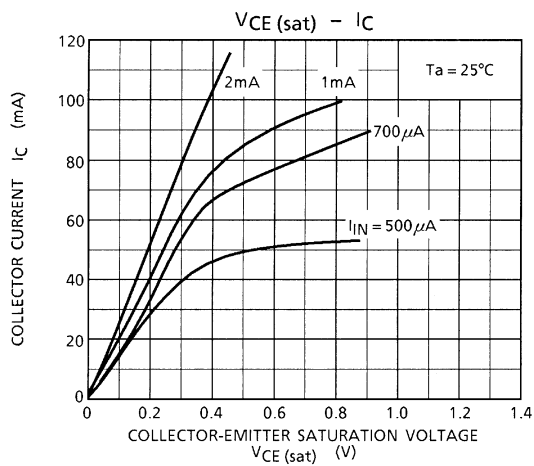
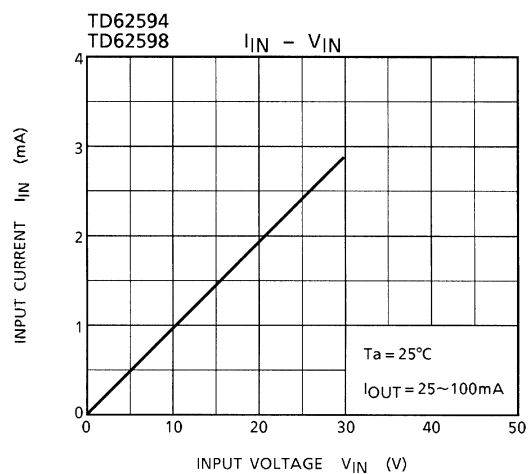
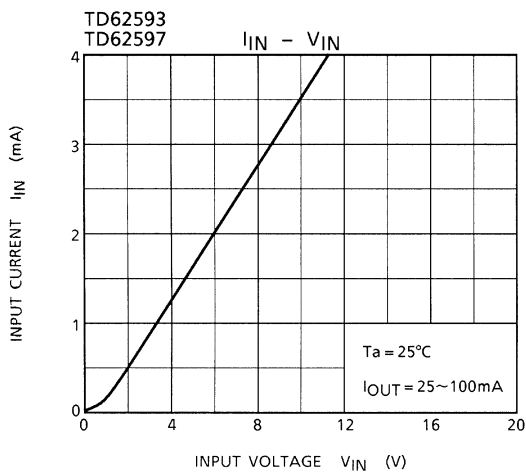
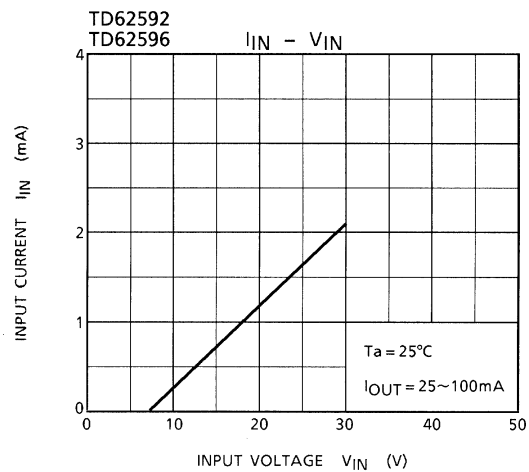
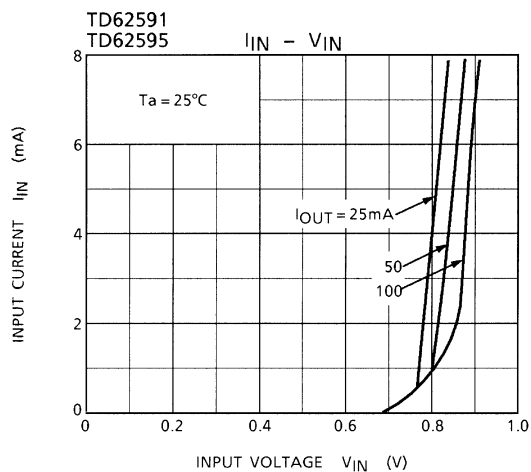
Note 3: C_L includes probe and jig capacitance

PRECAUTIONS for USING

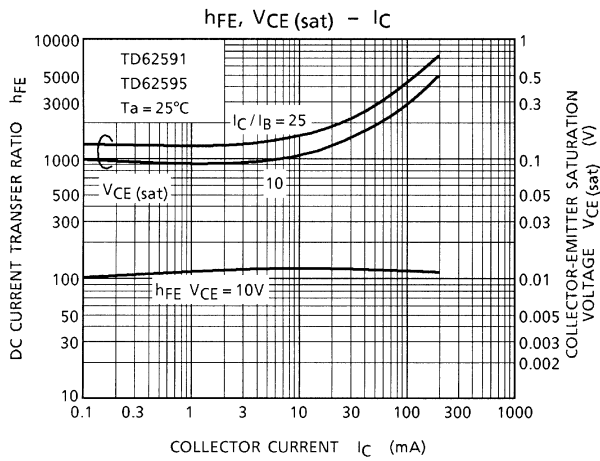
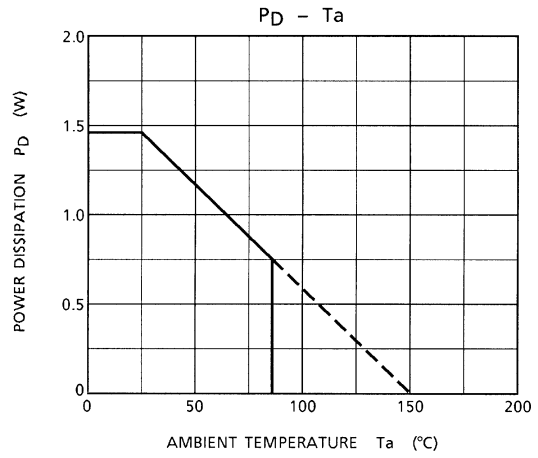
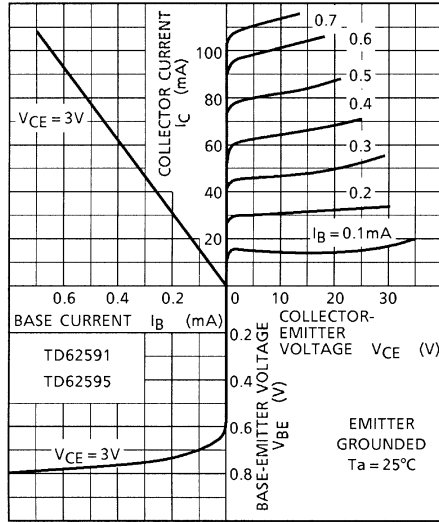
This IC does not integrate protection circuits such as overcurrent and overvoltage protectors.

Thus, if excess current or voltage is applied to the IC, the IC may be damaged. Please design the IC so that excess current or voltage will not be applied to the IC.

Utmost care is necessary in the design of the output line, V_{CC} and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.



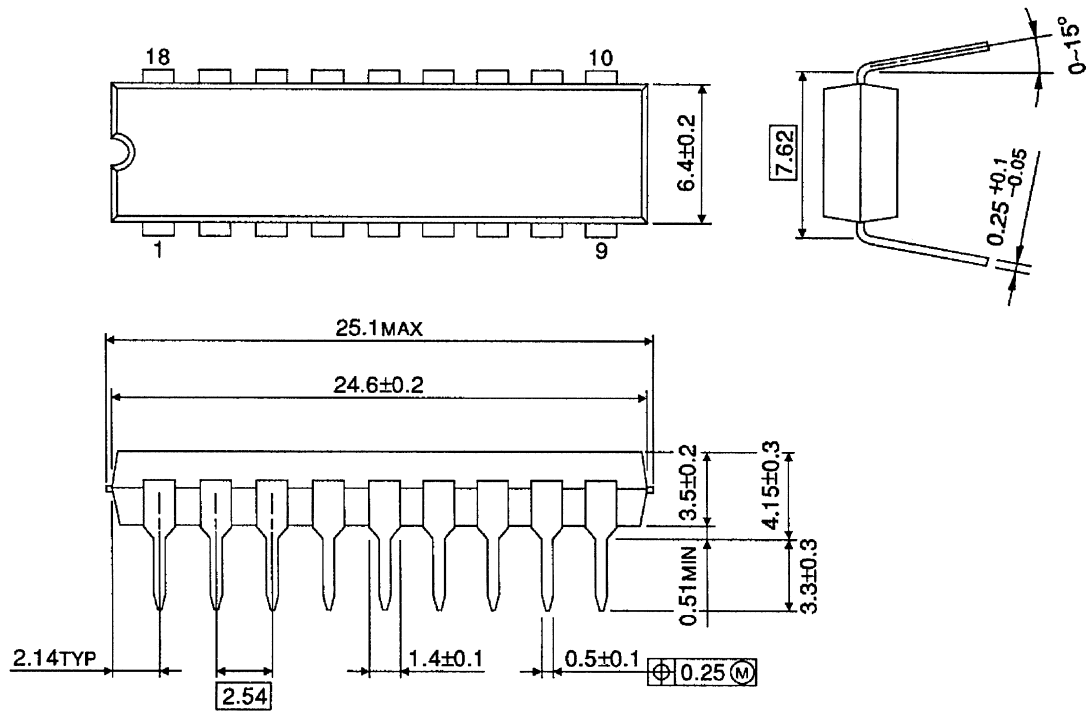
STATIC CHARACTERISTICS



PACKAGE DIMENSIONS

DIP18-P-300-2.54D

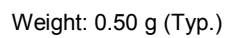
Unit: mm



Weight: 1.47 g (Typ.)

SOP18-P-375-1.27

Unit: mm



About solderability, following conditions were confirmed

- Solderability

- (1) Use of Sn-63Pb solder Bath

- solder bath temperature = 230°C
 - dipping time = 5 seconds
 - the number of times = once
 - use of R-type flux

- (2) Use of Sn-3.0Ag-0.5Cu solder Bath

- solder bath temperature = 245°C
 - dipping time = 5 seconds
 - the number of times = once
 - use of R-type flux

RESTRICTIONS ON PRODUCT USE

030619EBA

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